## **HEF4555B**

# 1-of-4 decoder/demultiplexer Rev. 5 — 18 November 2011

Product data sheet

#### 1. **General description**

The HEF4555B contains two 1-of-4 decoders/demultiplexers. Each has two address inputs (nA0 and nA1, an active LOW enable input (nE) and four mutually exclusive outputs which are active HIGH (nY0 to nY3). When used as a decoder, nE when HIGH, forces nY0 to nY3 LOW. When used as a demultiplexer, the appropriate output is selected by the information on nA0 and nA1 with nE as data input. All unselected outputs are LOW.

It operates over a recommended V<sub>DD</sub> power supply range of 3 V to 15 V referenced to V<sub>SS</sub> (usually ground). Unused inputs must be connected to V<sub>DD</sub>, V<sub>SS</sub>, or another input.

#### **Features and benefits** 2.

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

## **Applications**

- Code conversion
- Address decoding
- Demultiplexing: when using the enable input as data input

#### **Ordering information** 4.

Table 1. **Ordering information** 

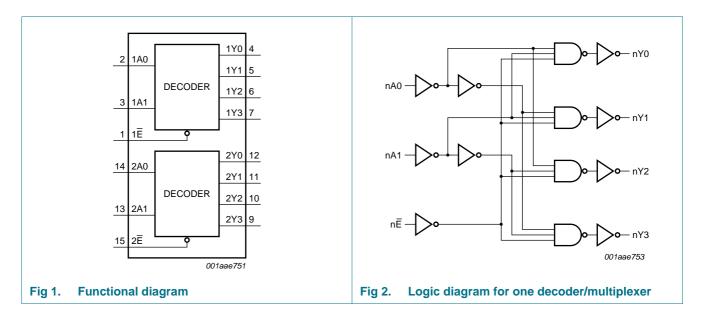
All types operate from -40 °C to +85 °C.

Type number	nber Package								
	Name	Description	Version						
HEF4555BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4						
HEF4555BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1						



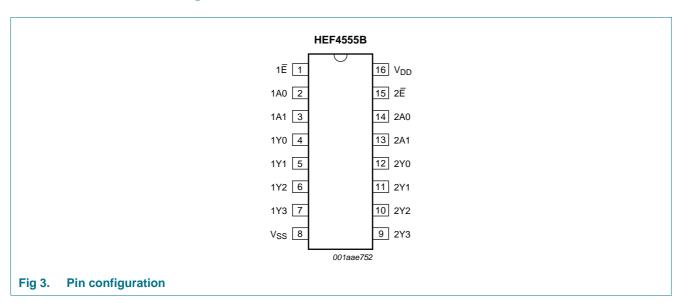
1-of-4 decoder/demultiplexer

## 5. Functional diagram



## 6. Pinning information

#### 6.1 Pinning



1-of-4 decoder/demultiplexer

## 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A0, 1A1, 2A0, 2A1	2, 3, 14, 13	address input
1E, 2E	1, 15	enable input (active LOW
1Y0, 1Y1, 1Y2, 1Y3, 2Y0, 2Y1, 2Y2, 2Y3	4, 5, 6, 7, 12, 11, 10, 9	output (active HIGH)
$V_{DD}$	16	supply voltage
V <sub>SS</sub>	8	ground (GND)

## 7. Functional description

Table 3. Function selection[1]

Inputs			Outputs	Outputs				
nE	nA0	nA1	nY0	nY1	nY2	nY3		
L	L	L	Н	L	L	L		
L	Н	L	L	Н	L	L		
L	L	Н	L	L	Н	L		
L	Н	Н	L	L	L	Н		
Н	X	Χ	L	L	L	L		

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care.

## 8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	M	in	Max	Unit
$V_{DD}$	supply voltage		-0	).5	+18	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-		±10	mA
VI	input voltage		-0	).5	$V_{DD} + 0.5$	V
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-		±10	mA
I <sub>I/O</sub>	input/output current		-		±10	mA
$I_{DD}$	supply current		-		50	mA
T <sub>stg</sub>	storage temperature		-6	65	+150	°C
T <sub>amb</sub>	ambient temperature		_4	10	+85	°C
P <sub>tot</sub>	total power dissipation	DIP16 package	<u>[1]</u> -		750	mW
		SO16 package	[2] _		500	mW
Р	power dissipation	per output	-		100	mW

<sup>[1]</sup> For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

<sup>[2]</sup> For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70  $^{\circ}\text{C}.$ 

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## 9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DD}$	supply voltage		3	-	15	V
$V_{I}$	input voltage		0	-	$V_{DD}$	V
$T_{amb}$	ambient temperature	in free air	-40	-	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	-	0.08	μs/V

## 10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$  V;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	T <sub>amb</sub> =	–40 °C	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = 85 °C		Unit
				Min	Max	Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	$ I_{O}  < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
$V_{IL}$	LOW-level input voltage	$ I_{O}  < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V <sub>OH</sub>	HIGH-level output voltage	$ I_{O}  < 1 \mu A;$	5 V	4.95	-	4.95	-	4.95	-	V
		$V_I = V_{SS}$ or $V_{DD}$	10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V <sub>OL</sub>	LOW-level output voltage	$ I_O  < 1 \mu A;$ $V_I = V_{SS} \text{ or } V_{DD}$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I <sub>OH</sub>	HIGH-level output current	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	mΑ
		$V_0 = 4.6 \text{ V}$	5 V	-	-0.52	-	-0.44	-	-0.36	mΑ
		$V_0 = 9.5 \text{ V}$	10 V	-	-1.3	-	-1.1	-	-0.9	mΑ
		V <sub>O</sub> = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mΑ
I <sub>OL</sub>	LOW-level output current	$V_0 = 0.4 \text{ V}$	5 V	0.52	-	0.44	-	0.36	-	mΑ
		$V_0 = 0.5 \text{ V}$	10 V	1.3	-	1.1	-	0.9	-	mΑ
		V <sub>O</sub> = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mΑ
I <sub>I</sub>	input leakage current	$V_{DD} = 15 \text{ V}$	15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
I <sub>DD</sub>	supply current	$I_{O} = 0 A;$	5 V	-	20	-	20	-	150	μΑ
		$V_I = V_{SS}$ or $V_{DD}$	10 V	-	40	-	40	-	300	μΑ
			15 V	-	80	-	80	-	600	μΑ
C <sub>I</sub>	input capacitance		-	-	-	-	7.5	-	-	pF

## 11. Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS} = 0 \text{ V}$ ;  $T_{amb} = 25 \text{ °C}$ ; for test circuit see <u>Figure 5</u>; unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	Extrapolation formula	Min	Тур	Max	Unit
t <sub>PHL</sub>	HIGH to LOW	$nAn \rightarrow nYn;$	5 V	[1] 88 ns + (0.55 ns/pF)C <sub>L</sub>	-	115	230	ns
	propagation delay	see <u>Figure 4</u>	10 V	34 ns + $(0.23 \text{ ns/pF})C_L$	-	45	90	ns
			15 V	22 ns + (0.16 ns/pF)C <sub>L</sub>	-	30	65	ns
		$\overline{\text{nE}} \rightarrow \text{nYn}$	5 V	98 ns + $(0.55 \text{ ns/pF})C_L$	-	125	250	ns
			10 V	39 ns + $(0.23 \text{ ns/pF})C_L$	-	50	95	ns
			15 V	22 ns + (0.16 ns/pF C <sub>L</sub>	-	30	65	ns
t <sub>PLH</sub>	LOW to HIGH		5 V	113 ns + (0.55 ns/pF)C <sub>L</sub>	-	140	280	ns
	propagation delay		10 V	44 ns + (0.23 ns/pF)C <sub>L</sub>	-	55	105	ns
			15 V	32 ns + $(0.16 \text{ ns/pF})C_L$	-	40	75	ns
		$n\overline{E} \rightarrow nYn$	5 V	123 ns + (0.55 ns/pF)C <sub>L</sub>	-	150	295	ns
			10 V	44 ns + (0.23 ns/pF)C <sub>L</sub>	-	55	110	ns
			15 V	32 ns + $(0.16 \text{ ns/pF})C_L$	-	40	75	ns
t <sub>t</sub>	transition time	on nYn	5 V	[1][2] 10 ns + (1.00 ns/pF)C <sub>L</sub>	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C <sub>L</sub>	-	30	60	ns
			15 V	6 ns + $(0.28 \text{ ns/pF})C_L$	-	20	40	ns

<sup>[1]</sup> The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

Table 8. Dynamic power dissipation P<sub>D</sub>

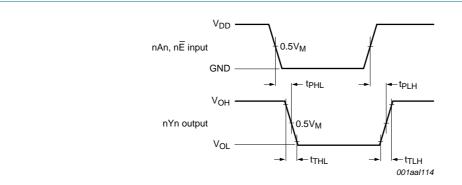
 $P_D$  can be calculated from the formulas shown.  $V_{SS} = 0 \text{ V}$ ;  $t_r = t_f \le 20 \text{ ns}$ ;  $T_{amb} = 25 \text{ °C}$ .

Symbol	Parameter	$V_{DD}$	Typical formula for P <sub>D</sub> (μW)	Where:
$P_D$	dynamic power	5 V	$P_D = 4500 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$f_i$ = input frequency in MHz,
	dissipation	10 V	$P_D = 18800 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	fo = output frequency in MHz,
		15 V	$P_D = 45700 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$C_L$ = output load capacitance in pF,
				$V_{DD}$ = supply voltage in V,
				$\Sigma(f_0 \times C_L)$ = sum of the outputs.

<sup>[2]</sup> Transition time  $t_t$  is the same as the HIGH to LOW and LOW to HIGH transition times  $t_{THL}$  and  $t_{TLH}$ .

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## 12. Waveforms



Measurement points are given in Table 9.

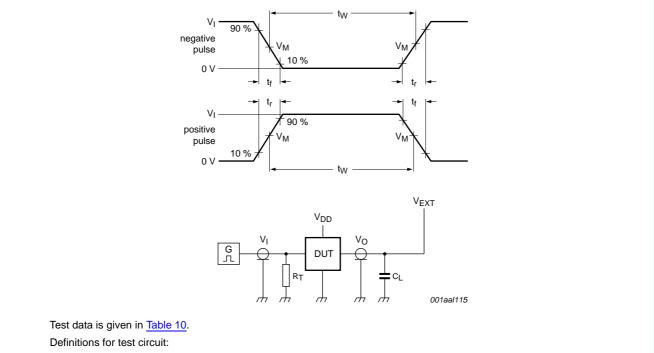
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig 4. Inputs nAn and nE to output nYn propagation delays

Table 9. Measurement points

Supply voltage	Input	Output		
$V_{DD}$	V <sub>M</sub>	V <sub>M</sub>		
5 V to 15 V	0.5V <sub>DD</sub>	0.5V <sub>DD</sub>		

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Device Under Test (DUT);

R<sub>L</sub> = Load resistance;

 $C_L$  = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator;

 $V_{EXT}$  = External voltage for measuring switching times.

Fig 5. Load circuitry for switching times

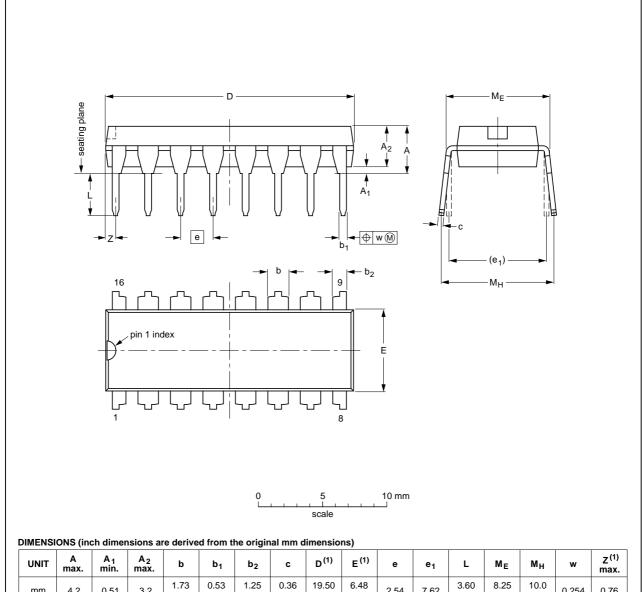
Table 10. Test data

Supply voltage	Input		Load	V <sub>EXT</sub>		
	$V_{l}$ $t_{r} = t_{f}$		CL	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>THL</sub> , t <sub>TLH</sub>	
5 V to 15 V	$V_{DD}$	≤ 20 ns	50 pF	open	$V_{DD}$	

## 13. Package outline

#### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

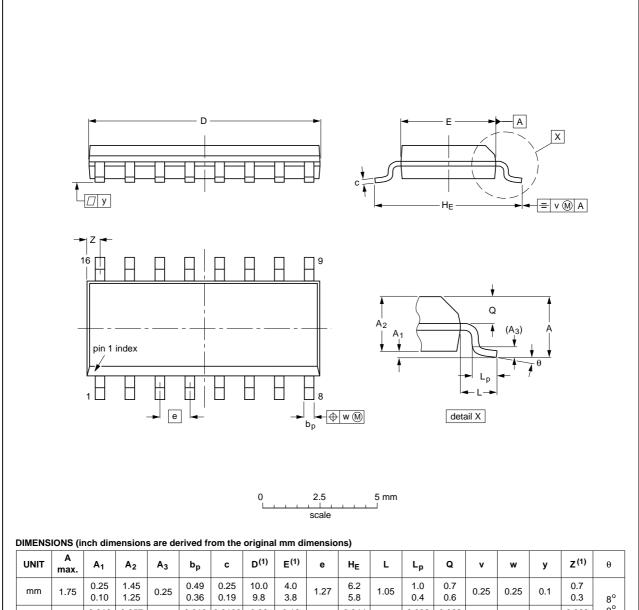
OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT38-4						<del>95-01-14</del> 03-02-13
	I .	L		1		

Fig 6. Package outline SOT38-4 (DIP16)

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SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	U	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	٦	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	1	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

	REFERENCES					
JEDEC	JEITA		PROJECTION	ISSUE DATE		
MS-012				<del>99-12-27</del> 03-02-19		
			V==20	Ma are		

Fig 7. Package outline SOT109-1 (SO16)

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## 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4555B v.5	20111118	Product data sheet	-	HEF4555B v.4
Modifications:	• <u>Table 6</u> : I <sub>OH</sub>	minimum values changed to n	naximum	
HEF4555B v.4	20100106	Product data sheet	-	HEF4555B_CNV v.3
HEF4555B_CNV v.3	19950101	Product specification	-	HEF4555B_CNV v.2
HEF4555B_CNV v.2	19950101	Product specification	-	-

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#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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